

## SGM8770 High Voltage, High Precision, Dual Differential Comparator

#### GENERAL DESCRIPTION

The SGM8770 is a dual, high precision differential voltage comparator optimized for high voltage operation. The device can operate from 2.8V to 36V single supply or from  $\pm 1.4$ V to  $\pm 18$ V dual power supplies. It consumes low supply current without being affected by the supply voltage. Input common mode voltage is 1.5V lower than  $\pm 1.4$ V s. The SGM8770 has an open-drain output structure that needs external pull-up resistor.

The SGM8770 is available in Green SOIC-8 and TDFN-3×3-8L packages. The SGM8770 is specified over the extended -40°C to +125°C temperature range.

#### **FEATURES**

Wide Supply Ranges
 Single Supply: 2.8V to 36V
 Dual Supplies: ±1.4V to ±18V

• Low Supply Current: 310μA (TYP)

Low Input Offset Voltage: 2.4mV (MAX)
 Low Input Bias Current: ±20pA (TYP)

• Minimum Input Common Mode Voltage: -V<sub>s</sub>

Maximum Differential Input Voltage: +36V/-36V

• Open-Drain Output Structure

• Low Output Saturation Voltage

• Supports CMOS or TTL Logic

-40°C to +125°C Operating Temperature Range

 Available in Green SOIC-8 and TDFN-3×3-8L Packages

#### **APPLICATIONS**

Power System Monitor
Medical Equipment
Industrial Application
Battery Management System



#### PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8770	SOIC-8	-40°C to +125°C	SGM8770XS8G/TR	SGM 8770XS8 XXXXX	Tape and Reel, 4000
SGINIO770	TDFN-3×3-8L	-40°C to +125°C	SGM8770XTDB8G/TR	SGM 8770DB XXXXX	Tape and Reel, 4000

#### MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.

2	<u>(XXXX</u>	
		Vendor Code
		Trace Code
		Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage, +V <sub>S</sub> to -V <sub>S</sub> 40V
Differential Input Voltage,  V <sub>ID</sub>  40V
Input/Output Voltage Range $(-V_S)$ - 0.3V to $(+V_S)$ + 0.3V
Junction Temperature+150°C
Storage Temperature Range65°C to +150°C
Lead Temperature (Soldering, 10s)+260°C
ESD Susceptibility
HBM2500V
MM400V
CDM1000V

#### RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range	40°C to +125°C
Power Supply Range	2.8V to 36V

#### **OVERSTRESS CAUTION**

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

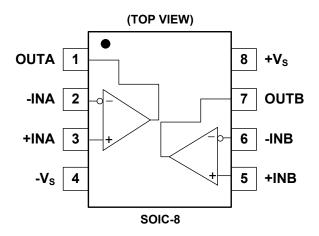
#### **ESD SENSITIVITY CAUTION**

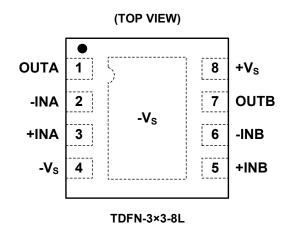
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

#### **DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

## **PIN CONFIGURATIONS**





## **ELECTRICAL CHARACTERISTICS**

(At  $T_A = +25^{\circ}C$ ,  $V_S = \pm 1.4V$  to  $\pm 18V$ , Full = -40°C to +125°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Input Offset Voltage	Vos	V <sub>CM</sub> = 0V	+25°C		0.6	2.4	mV
Imput Onset Voltage	Vos	V <sub>CM</sub> – UV	Full			2.8	mv
Input Bias Current	I <sub>B</sub>	V <sub>CM</sub> = 0V	+25°C		±20	±240	pА
Input Offset Current	Ios	V <sub>CM</sub> = 0V	+25°C		±20	±320	pА
Maximum Differential Input Voltage	V <sub>ID</sub>		Full			(+V <sub>S</sub> ) - (-V <sub>S</sub> )	V
Maximum Input Difference Bios Current	11 1	$V_S = \pm 18V, V_{ID} = \pm 18V$	+25°C		2.2	3	
Maximum Input Difference Bias Current	I <sub>ID</sub>	$V_S = \pm 18V$ , $V_{ID} = \pm 18V$	Full			5	μA
Input Common Mode Voltage Range (1)	V <sub>CM</sub>		Full	-Vs		(+V <sub>S</sub> ) - 1.5	V
Common Mada Baiastian Batia	CMDD	$V_S = \pm 18V$ , $V_{CM} = -V_S$ to $(+V_S) - 1.5V$	+25°C	96	116		dB
ommon Mode Rejection Ratio	CMRR		Full	80			
Barres Committee Balletting Batter	PSRR	V <sub>S</sub> = 2.8V to 36V	+25°C	98	116		dB
Power Supply Rejection Ratio			Full	95			
Cimal Differential Value Applifestion		$V_S = 36V$ , $V_{OUT} = 0.1V$ to 28.8V,	+25°C	90	100		JD.
Large-Signal Differential Voltage Amplification	A <sub>VD</sub>	$R_L = 120k\Omega$ to $V_S$	Full	87			dB
Outrot Valtage Cuitage from Deil	.,	I - 0 - 0 - 0 - 0 - 0 - 0 - 0 - 0 - 0 -	+25°C		200	280	\/
Output Voltage Swing from Rail	V <sub>OL</sub>	$I_{SINK} = 8mA$ , $V_{ID} = -0.2V$	Full			410	mV
Output Short-Circuit Current	I <sub>SINK</sub>	$V_{OL} = (-V_S) + 1.5V, V_{ID} = -0.2V$	+25°C	24	36		mA
		V 0.0V V 0.0V	+25°C		0.4	0.8	
High Loyal Output Current		$V_{OH} = 2.8V, V_{ID} = 0.2V$	Full			1	μA
High-Level Output Current	I <sub>OH</sub>		+25°C		6	9	μА
		$V_{OH} = 36V, V_{ID} = 0.2V$	Full			62	
Tatal Committee Committee			+25°C		310	380	
Total Supply Current	I <sub>S</sub>	I <sub>OUT</sub> = 0mA	Full			430	μA

### **SWITCHING CHARACTERISTICS**

(At  $T_A$  = +25°C,  $V_S$  = ±2.5V,  $C_L$  = 15pF  $^{(2)}$ , unless otherwise specified.)

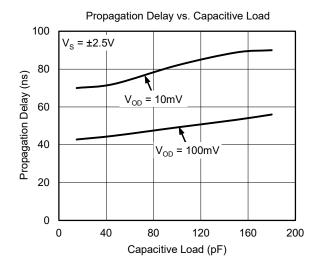
PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Dronggation Doloy (High to Law)		Overdrive = 10mV	+25°C		75		ns
Propagation Delay (High to Low)	t <sub>PHL</sub>	Overdrive = 100mV	+25°C		45		ns
Fall Time	+	Overdrive = 10mV	+25°C		15		ns
Fall Tillie	l <sub>FALL</sub>	Overdrive = 100mV	+25°C		15		ns

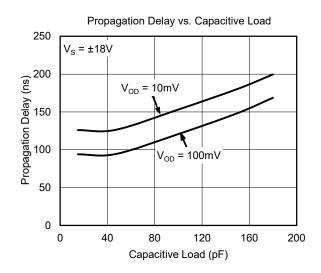
#### NOTES:

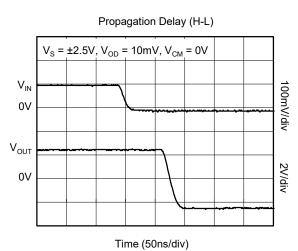
- 1. Any input voltage should not be lower than  $(-V_S)$  0.3V. The maximum input common mode voltage is  $(+V_S)$  1.5V, but it will not be damaged when the upper limit of the input voltage reaches 36V.
- 2. C<sub>L</sub>: Load capacitance (jig and probe included).

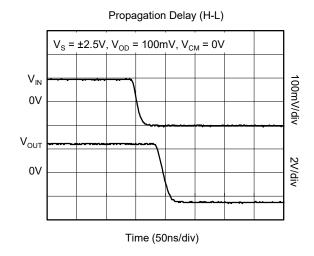
## TYPICAL PERFORMANCE CHARACTERISTICS

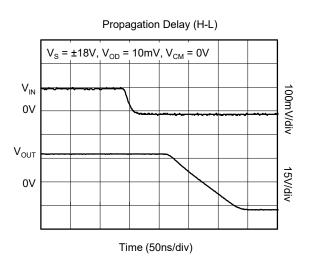
At  $T_A = +25$ °C,  $V_S = \pm 18$ V and  $C_L = 15$ pF, unless otherwise noted.

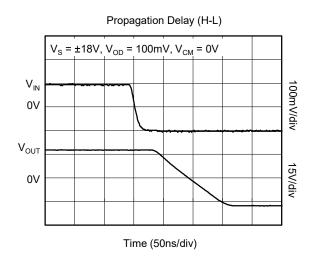






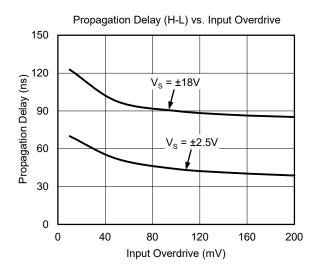


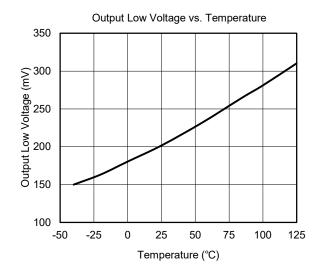


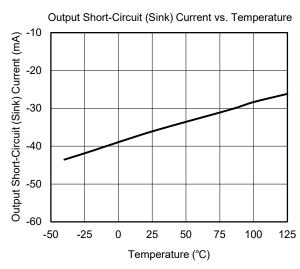


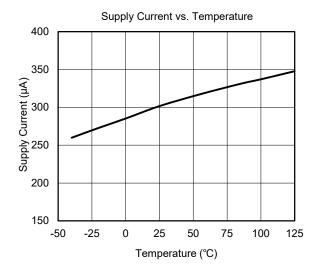
## **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

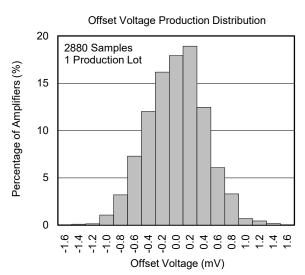
At  $T_A = +25$ °C,  $V_S = \pm 18$ V and  $C_L = 15$ pF, unless otherwise noted.











#### **DETAILED DESCRIPTION**

The SGM8770 is a dual, high precision, low power comparator. The wide input voltage range and power supply range make the device a good choice for industrial equipment. Open-drain structure needs external pull-up resistor. The SGM8770 can be compatible with CMOS and TTL logics.

#### **Output Structure**

In Figure 1, the SGM8770 has an open-drain output stage. When output is changed from logic high to low, the changed sink current pulls output pin to logic low. Beginning this transition, larger sink current is used to create a high slew rate transit from high to low. Once the output voltage reaches  $V_{\text{OL}}$ , it will reduce the sink current to a just right value to maintain the  $V_{\text{OL}}$  static condition. This current-driven open-drain output stage will significantly reduce the power consumption in application system.

If low slew rate transition is needed in system design, adjusting the load capacitance will change the slew rate. The heavier capacitive load will slow down the output voltage transition. This feature will be used to reduce the interference generated by fast edge of transition between 1 and 0 in noise-sensitive system.

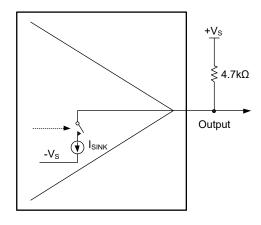


Figure 1. Open-Drain Output Structure

#### APPLICATION INFORMATION

#### Layout and Bypassing

Good power supply decoupling, layout and grounding are very important for SGM8770 to realize the full high-speed capabilities in system, following skills will be used:

 $\bullet$  A 0.1µF to 4.7µF range ceramic capacitor is used to provide good power supply decoupling. This ceramic capacitor must be placed as close to +V\_S pin as possible.

- For grounding, unbroken and low-inductance ground plane is a good choice.
- For Layout, use short PCB trace to avoid unwanted parasitic feedback around the comparator. SGM8770 must be soldered directly to the PCB and the socket is not recommended.

# High Voltage, High Precision, Dual Differential Comparator

## **SGM8770**

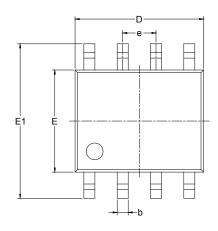
## **REVISION HISTORY**

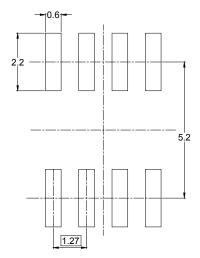
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (DECEMBER 2018) to REV.A	Page
Changed from product preview to production data	All

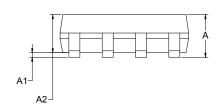


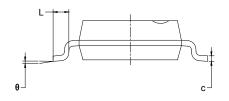
# PACKAGE OUTLINE DIMENSIONS SOIC-8





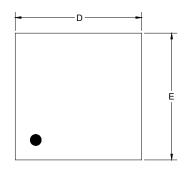
RECOMMENDED LAND PATTERN (Unit: mm)

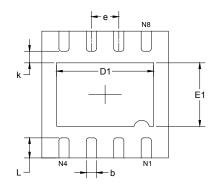




Symbol		nsions meters	Dimensions In Inches		
,	MIN	MAX	MIN	MAX	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
Е	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.27	1.27 BSC 0.050		BSC	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

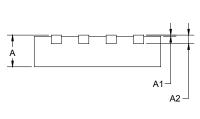
## **PACKAGE OUTLINE DIMENSIONS** TDFN-3×3-8L



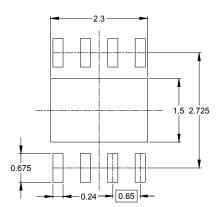








**SIDE VIEW** 

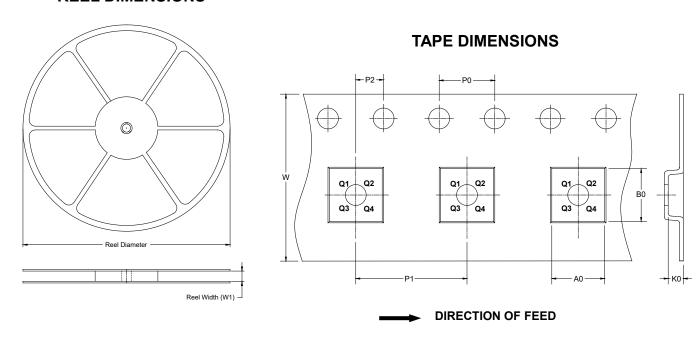


RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	-	nsions meters	Dimensions In Inches			
	MIN	MAX	MIN	MAX		
Α	0.700	0.800	0.028	0.031		
A1	0.000	0.050	0.000	0.002		
A2	0.203	REF	0.008 REF			
D	2.900	3.100	0.114	0.122		
D1	2.200	2.400	0.087	0.094		
E	2.900	3.100	0.114	0.122		
E1	1.400	1.600	0.055	0.063		
k	0.200	0.200 MIN		MIN		
b	0.180	0.300	0.007	0.012		
е	0.650	) TYP	0.026	TYP		
L	0.375	0.575 0.015		0.023		

## TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**

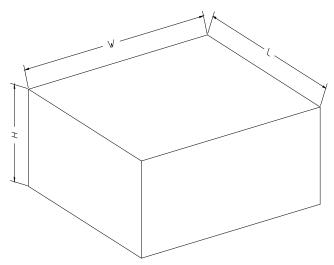


NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
TDFN-3×3-8L	13"	12.4	3.35	3.35	1.13	4.0	8.0	2.0	12.0	Q1

#### **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5